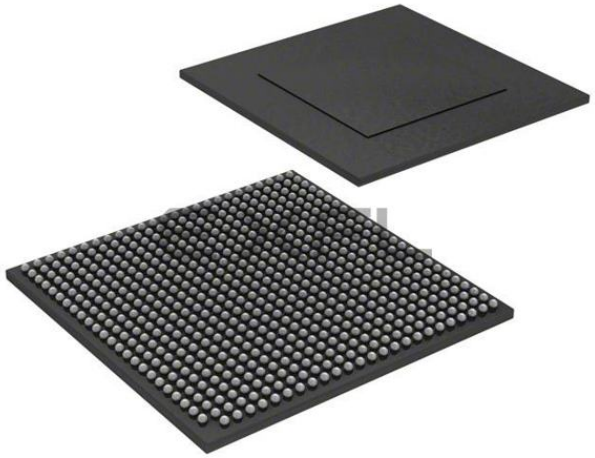

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	ARM® Cortex®-A9
Number of Cores/Bus Width	2 Core, 32-Bit
Speed	1.0GHz
Co-Processors/DSP	Multimedia; NEON™ SIMD
RAM Controllers	LPDDR2, LVDDR3, DDR3
Graphics Acceleration	Yes
Display & Interface Controllers	Keypad, LCD
Ethernet	10/100/1000Mbps (1)
SATA	SATA 3Gbps (1)
USB	USB 2.0 + PHY (4)
Voltage - I/O	1.8V, 2.5V, 2.8V, 3.3V
Operating Temperature	-40°C ~ 125°C (TJ)
Security Features	ARM TZ, Boot Security, Cryptography, RTIC, Secure Fusebox, Secure JTAG, Secure Memory, Secure RTC, Tamper Detection
Package / Case	624-FBGA, FCBGA
Supplier Device Package	624-FCBGA (21x21)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx6d6avt10adr

- Gigabit Ethernet Controller (IEEE1588 compliant), 10/100/1000[1] Mbps
- Four Pulse Width Modulators (PWM)
- System JTAG Controller (SJC)
- GPIO with interrupt capabilities
- 8x8 Key Pad Port (KPP)
- Sony Philips Digital Interconnect Format (SPDIF), Rx and Tx
- Two Controller Area Network (FlexCAN), 1 Mbps each
- Two Watchdog timers (WDOG)
- Audio MUX (AUDMUX)
- MLB (MediaLB) provides interface to MOST Networks (150 Mbps) with the option of DTCP cipher accelerator

The i.MX 6Dual/6Quad processors integrate advanced power management unit and controllers:

- Provide PMU, including LDO supplies, for on-chip resources
- Use Temperature Sensor for monitoring the die temperature
- Support DVFS techniques for low power modes
- Use Software State Retention and Power Gating for ARM and MPE
- Support various levels of system power modes
- Use flexible clock gating control scheme

The i.MX 6Dual/6Quad processors use dedicated hardware accelerators to meet the targeted multimedia performance. The use of hardware accelerators is a key factor in obtaining high performance at low power consumption numbers, while having the CPU core relatively free for performing other tasks.

The i.MX 6Dual/6Quad processors incorporate the following hardware accelerators:

- VPU—Video Processing Unit
- IPUv3H—Image Processing Unit version 3H (2 IPUs)
- GPU3Dv4—3D Graphics Processing Unit (OpenGL ES 2.0) version 4
- GPU2Dv2—2D Graphics Processing Unit (BitBlt)
- GPUVG—OpenVG 1.1 Graphics Processing Unit
- ASRC—Asynchronous Sample Rate Converter

Security functions are enabled and accelerated by the following hardware:

- ARM TrustZone including the TZ architecture (separation of interrupts, memory mapping, etc.)
- SJC—System JTAG Controller. Protecting JTAG from debug port attacks by regulating or blocking the access to the system debug features.
- CAAM—Cryptographic Acceleration and Assurance Module, containing 16 KB secure RAM and True and Pseudo Random Number Generator (NIST certified)
- SNVS—Secure Non-Volatile Storage, including Secure Real Time Clock

1. The theoretical maximum performance of 1 Gbps ENET is limited to 470 Mbps (total for Tx and Rx) due to internal bus throughput limitations. The actual measured performance in optimized environment is up to 400 Mbps. For details, see the ERR004512 erratum in the i.MX 6Dual/6Quad errata document (IMX6DQCE).

Table 2. i.MX 6Dual/6Quad Modules List (continued)

Block Mnemonic	Block Name	Subsystem	Brief Description
WDOG-2 (TZ)	Watchdog (TrustZone)	Timer Peripherals	The TrustZone Watchdog (TZ WDOG) timer module protects against TrustZone starvation by providing a method of escaping normal mode and forcing a switch to the TZ mode. TZ starvation is a situation where the normal OS prevents switching to the TZ mode. Such a situation is undesirable as it can compromise the system's security. Once the TZ WDOG module is activated, it must be serviced by TZ software on a periodic basis. If servicing does not take place, the timer times out. Upon a time-out, the TZ WDOG asserts a TZ mapped interrupt that forces switching to the TZ mode. If it is still not served, the TZ WDOG asserts a security violation signal to the CSU. The TZ WDOG module cannot be programmed or deactivated by a normal mode Software.
EIM	NOR-Flash /PSRAM interface	Connectivity Peripherals	The EIM NOR-FLASH / PSRAM provides: • Support 16-bit (in muxed IO mode only) PSRAM memories (sync and async operating modes), at slow frequency • Support 16-bit (in muxed IO mode only) NOR-Flash memories, at slow frequency • Multiple chip selects
XTALOSC	Crystal Oscillator interface	—	The XTALOSC module enables connectivity to external crystal oscillator device. In a typical application use-case, it is used for 24 MHz oscillator.

3.1 Special Signal Considerations

The package contact assignments can be found in Section 6, "Package Information and Contact Assignments." Signal descriptions are defined in the i.MX 6Dual/6Quad reference manual (IMX6DQRM). Special signal consideration information is contained in the Hardware Development Guide for i.MX 6Quad, 6Dual, 6DualLite, 6Solo Families of Applications Processors (IMX6DQ6SDLHDG).

3.2 Recommended Connections for Unused Analog Interfaces

The recommended connections for unused analog interfaces can be found in the section, "Unused analog interfaces," of the Hardware Development Guide for i.MX 6Quad, 6Dual, 6DualLite, 6Solo Families of Applications Processors (IMX6DQ6SDLHDG).

4.1.3 Operating Ranges

Table 6 provides the operating ranges of the i.MX 6Dual/6Quad processors.

Table 6. Operating Ranges

Parameter Description	Symbol	Min	Typ	Max[1]	Unit	Comment[2]
Run mode: LDO enabled	VDD_ARM_IN VDD_ARM23_IN[3]	1.35[4]	—	1.5	V	LDO Output Set Point (VDD_ARM_CAP[5]) of 1.225 V minimum for operation up to 852 MHz or 996 MHz (depending on the device speed grade).
		1.275[4]	—	1.5	V	LDO Output Set Point (VDD_ARM_CAP[5]) of 1.150 V minimum for operation up to 792 MHz.
		1.05[4]	—	1.5	V	LDO Output Set Point (VDD_ARM_CAP[5]) of 0.925 V minimum for operation up to 396 MHz.
	VDD_SOC_IN[6]	1.350[4]	—	1.5	V	264 MHz < VPU ≤ 352 MHz; VDDSOC and VDDPU LDO outputs (VDD_SOC_CAP and VDD_PU_CAP) require 1.225 V minimum.
		1.275[4,7]	—	1.5	V	VPU ≤ 264 MHz; VDDSOC and VDDPU LDO outputs (VDD_SOC_CAP and VDD_PU_CAP) require 1.15 V minimum.
Run mode: LDO bypassed[8]	VDD_ARM_IN VDD_ARM23_IN[3]	1.225	—	1.3	V	LDO bypassed for operation up to 852 MHz or 996 MHz (depending on the device speed grade).
		1.150	—	1.3	V	LDO bypassed for operation up to 792 MHz.
		0.925	—	1.3	V	LDO bypassed for operation up to 396 MHz.
	VDD_SOC_IN[6]	1.225	—	1.3	V	264 MHz < VPU ≤ 352 MHz
		1.15	—	1.3	V	VPU ≤ 264 MHz
Standby/DSM mode	VDD_ARM_IN VDD_ARM23_IN[3]	0.9	—	1.3	V	See Table 9, "Stop Mode Current and Power Consumption," on page 26.
	VDD_SOC_IN	0.9	—	1.3	V	
VDD_HIGH internal regulator	VDD_HIGH_IN[9]	2.7	—	3.3	V	Must match the range of voltages that the rechargeable backup battery supports.
Backup battery supply range	VDD_SNVS_IN[9]	2.8	—	3.3	V	Should be supplied from the same supply as VDD_HIGH_IN, if the system does not require keeping real time and other data on OFF state.
USB supply voltages	USB_OTG_VBUS	4.4	—	5.25	V	—
	USB_H1_VBUS	4.4	—	5.25	V	—
DDR I/O supply	NVCC_DRAM	1.14	1.2	1.3	V	LPDDR2
		1.425	1.5	1.575	V	DDR3
		1.283	1.35	1.45	V	DDR3_L
Supply for RGMII I/O power group[10]	NVCC_RGMII	1.15	—	2.625	V	• 1.15 V – 1.30 V in HSIC 1.2 V mode • 1.43 V – 1.58 V in RGMII 1.5 V mode • 1.70 V – 1.90 V in RGMII 1.8 V mode • 2.25 V – 2.625 V in RGMII 2.5 V mode

[10] All digital I/O supplies (NVCC_xxxx) must be powered under normal conditions whether the associated I/O pins are in use or not, and associated I/O pins need to have a pull-up or pull-down resistor applied to limit any floating gate current.

[11] This supply also powers the pre-drivers of the DDR I/O pins; therefore, it must always be provided, even when LVDS is not used.

4.1.4 External Clock Sources

Each i.MX 6Dual/6Quad processor has two external input system clocks: a low frequency (RTC_XTALI) and a high frequency (XTALI).

The RTC_XTALI is used for low-frequency functions. It supplies the clock for wake-up circuit, power-down real time clock operation, and slow system and watchdog counters. The clock input can be connected to either an external oscillator or a crystal using the internal oscillator amplifier. Additionally, there is an internal ring oscillator, that can be used instead of RTC_XTALI when accuracy is not important.

The system clock input XTALI is used to generate the main system clock. It supplies the PLLs and other peripherals. The system clock input can be connected to either an external oscillator or a crystal using the internal oscillator amplifier.

NOTE

The internal RTC oscillator does not provide an accurate frequency and is affected by process, voltage and temperature variations. Freescale strongly recommends using an external crystal as the RTC_XTALI reference. If the internal oscillator is used instead, careful consideration should be given to the timing implications on all of the SoC modules dependent on this clock.

Table 7 shows the interface frequency requirements.

Table 7. External Input Clock Frequency

Parameter Description	Symbol	Min	Typ	Max	Unit
RTC_XTALI Oscillator[1,2]	f_{ckil}	—	32.768[3]/32.0	—	kHz
XTALI Oscillator[4,2]	f_{xtal}	—	24	—	MHz

[1] External oscillator or a crystal with internal oscillator amplifier.

[2] The required frequency stability of this clock source is application dependent. For recommendations, see the Hardware Development Guide for i.MX 6Dual, 6Quad, 6Solo, 6DualLite Families of Applications Processors (IMX6DQ6SDLHDG).

[3] Recommended nominal frequency 32.768 kHz.

[4] External oscillator or a fundamental frequency crystal with internal oscillator amplifier.

The typical values shown in Table 7 are required for use with Freescale BSPs to ensure precise time keeping and USB operation. For RTC_XTALI operation, two clock sources are available:

- On-chip 40 kHz ring oscillator: This clock source has the following characteristics:
  - Approximately 25 µA more Idd than crystal oscillator
  - Approximately ±50% tolerance
  - No external component required
  - Starts up quicker than 32 kHz crystal oscillator
- External crystal oscillator with on-chip support circuit

Table 9. Stop Mode Current and Power Consumption (continued)

Mode	Test Conditions	Supply	Typical[1]	Unit
STOP_ON	• ARM LDO set to 0.9 V • SoC and PU LDOs set to 1.225 V • HIGH LDO set to 2.5 V • PLLs disabled • DDR is in self refresh	VDD_ARM_IN (1.4 V)	7.5	mA
		VDD_SOC_IN (1.4 V)	22	mA
		VDD_HIGH_IN (3.0 V)	3.7	mA
		Total	52	mW
STOP_OFF	• ARM LDO set to 0.9 V • SoC LDO set to 1.225 V • PU LDO is power gated • HIGH LDO set to 2.5 V • PLLs disabled • DDR is in self refresh	VDD_ARM_IN (1.4 V)	7.5	mA
		VDD_SOC_IN (1.4 V)	13.5	mA
		VDD_HIGH_IN (3.0 V)	3.7	mA
		Total	41	mW
STANDBY	• ARM and PU LDOs are power gated • SoC LDO is in bypass • HIGH LDO is set to 2.5 V • PLLs are disabled • Low voltage • Well Bias ON • Crystal oscillator is enabled	VDD_ARM_IN (0.9 V)	0.1	mA
		VDD_SOC_IN (0.9 V)	13	mA
		VDD_HIGH_IN (3.0 V)	3.7	mA
		Total	22	mW
Deep Sleep Mode (DSM)	• ARM and PU LDOs are power gated • SoC LDO is in bypass • HIGH LDO is set to 2.5 V • PLLs are disabled • Low voltage • Well Bias ON • Crystal oscillator and bandgap are disabled	VDD_ARM_IN (0.9 V)	0.1	mA
		VDD_SOC_IN (0.9 V)	2	mA
		VDD_HIGH_IN (3.0 V)	0.5	mA
		Total	3.4	mW
SNVS Only	• VDD_SNVS_IN powered • All other supplies off • SRTC running	VDD_SNVS_IN (2.8V)	41	µA
		Total	115	µW

1 The typical values shown here are for information only and are not guaranteed. These values are average values measured on a worst-case wafer at 25°C.

4.1.7 USB PHY Current Consumption

4.1.7.1 Power Down Mode

In power down mode, everything is powered down, including the VBUS valid detectors, typ condition. Table 10 shows the USB interface current consumption in power down mode.

Table 10. USB PHY Current Consumption in Power Down Mode

	VDD_USB_CAP (3.0 V)	VDD_HIGH_CAP (2.5 V)	NVCC_PLL_OUT (1.1 V)
Current	5.1 µA	1.7 µA	<0.5 µA

NOTE

The currents on the VDD_HIGH_CAP and VDD_USB_CAP were identified to be the voltage divider circuits in the USB-specific level shifters.

4.1.8 SATA Typical Power Consumption

Table 11 provides SATA PHY currents for certain Tx operating modes.

NOTE

Tx power consumption values are provided for a single transceiver. If T = single transceiver power and C = Clock module power, the total power required for N lanes = N x T + C.

Table 11. SATA PHY Current Drain

Mode	Test Conditions	Supply	Typical Current	Unit
P0: Full-power state[1]	Single Transceiver	SATA_VP	11	mA
		SATA_VPH	13	
	Clock Module	SATA_VP	6.9	
		SATA_VPH	6.2	
P0: Mobile[2]	Single Transceiver	SATA_VP	11	mA
		SATA_VPH	11	
	Clock Module	SATA_VP	6.9	
		SATA_VPH	6.2	
P0s: Transmitter idle	Single Transceiver	SATA_VP	9.4	mA
		SATA_VPH	2.9	
	Clock Module	SATA_VP	6.9	
		SATA_VPH	6.2	

4.8.2 DDR I/O Output Buffer Impedance

The LPDDR2 interface fully complies with JESD209-2B LPDDR2 JEDEC standard release June, 2009. The DDR3 interface fully complies with JESD79-3D DDR3 JEDEC standard release April, 2008.

Table 35 shows DDR I/O output buffer impedance of i.MX 6Dual/6Quad processors.

Table 35. DDR I/O Output Buffer Impedance

Parameter	Symbol	Test Conditions	Typical		Unit
			NVCC_DRAM=1.5 V (DDR3) DDR_SEL=11	NVCC_DRAM=1.2 V (LPDDR2) DDR_SEL=10	
Output Driver Impedance	Rdrv	Drive Strength (DSE) =			Ω
		000	Hi-Z	Hi-Z	
		001	240	240	
		010	120	120	
		011	80	80	
		100	60	60	
		101	48	48	
		110	40	40	
		111	34	34	

Note:

1. Output driver impedance is controlled across PVTs using ZQ calibration procedure.
2. Calibration is done against 240 W external reference resistor.
3. Output driver impedance deviation (calibration accuracy) is ±5% (max/min impedance) across PVTs.

4.8.3 LVDS I/O Output Buffer Impedance

The LVDS interface complies with TIA/EIA 644-A standard. See, TIA/EIA STANDARD 644-A, “Electrical Characteristics of Low Voltage Differential Signaling (LVDS) Interface Circuits” for details.

4.8.4 MLB 6-Pin I/O Differential Output Impedance

Table 36 shows MLB 6-pin I/O differential output impedance of i.MX 6Dual/6Quad processors.

Table 36. MLB 6-Pin I/O Differential Output Impedance

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Differential Output Impedance	Z_O	—	1.6	—	—	kΩ

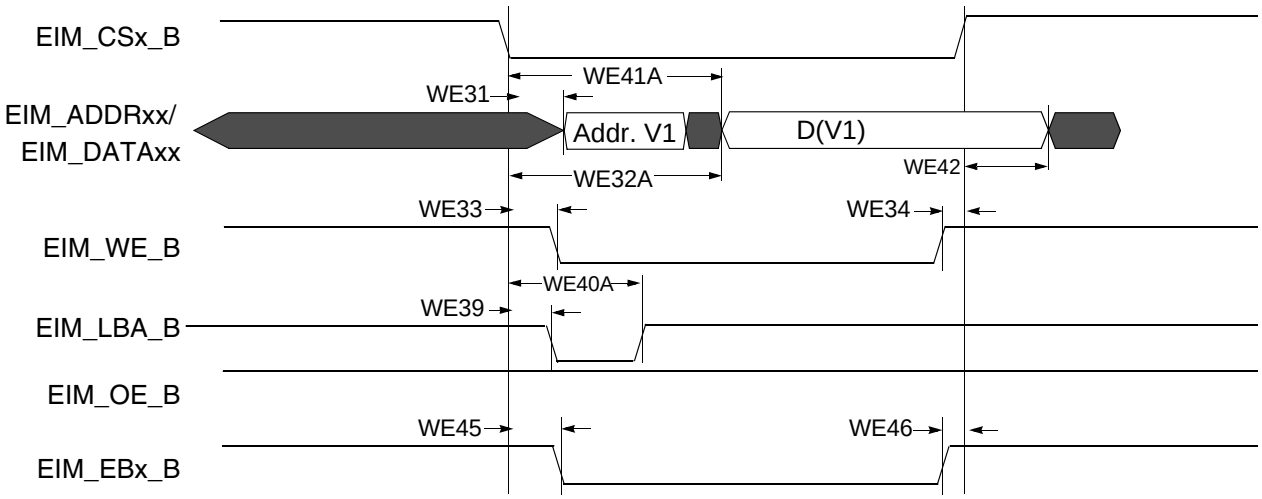

Figure 21. Asynchronous A/D Muxed Write Access

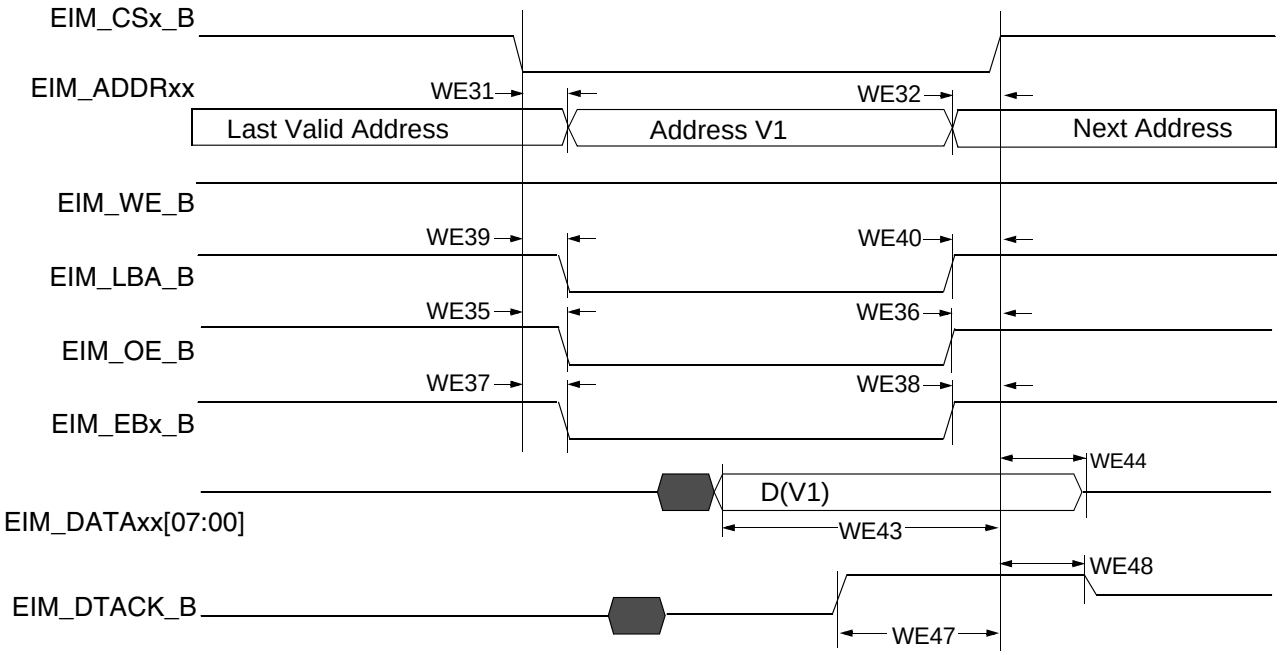

Figure 22. DTACK Mode Read Access (DAP=0)

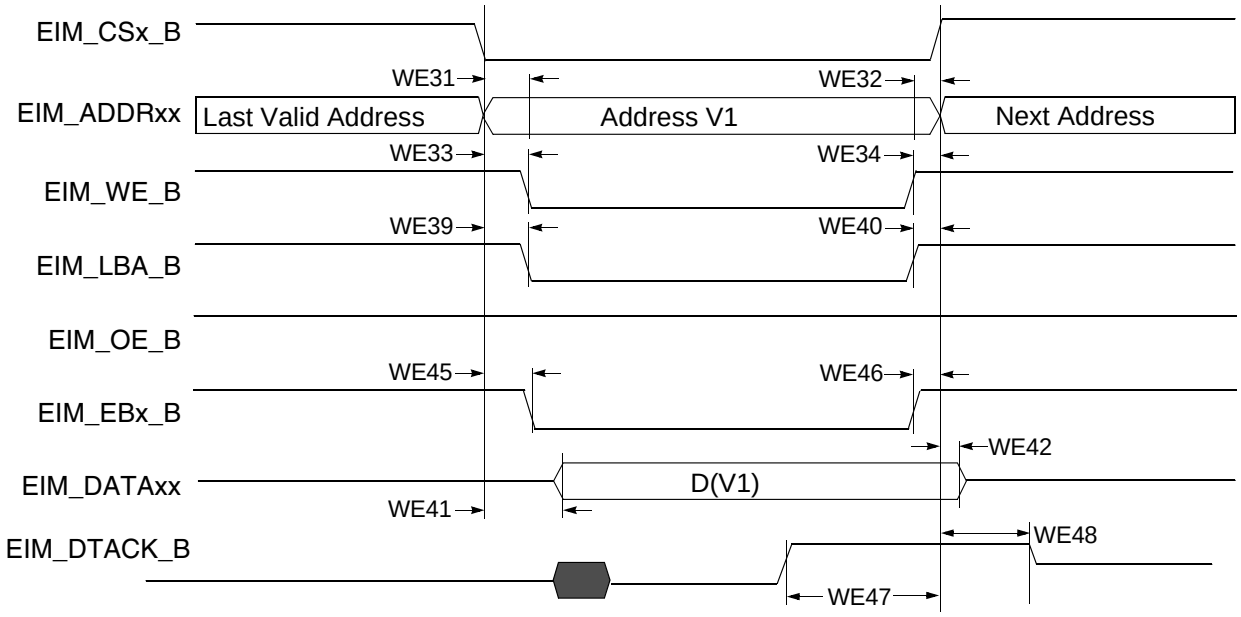

Figure 23. DTACK Mode Write Access (DAP=0)

Table 41. EIM Asynchronous Timing Parameters Relative to Chip Select[1, 2]

Ref No.	Parameter	Determination by Synchronous measured parameters	Min	Max	Unit
WE31	EIM_CSx_B valid to Address Valid	WE4-WE6-CSA×t	-3.5-CSA×t	3.5-CSA×t	ns
WE32	Address Invalid to EIM_CSx_B Invalid	WE7-WE5-CSN×t	-3.5-CSN×t	3.5-CSN×t	ns
WE32A (muxed A/D)	EIM_CSx_B valid to Address Invalid	t+WE4-WE7+ (ADVN+ADVA+1-CSA)×t	t - 3.5+(ADVN+ADVA+1-CSA)×t	t + 3.5+(ADVN+ADVA+1-CSA)×t	ns
WE33	EIM_CSx_B Valid to EIM_WE_B Valid	WE8-WE6+(WEA-WCSA)×t	-3.5+(WEA-WCSA)×t	3.5+(WEA-WCSA)×t	ns
WE34	EIM_WE_B Invalid to EIM_CSx_B Invalid	WE7-WE9+(WEN-WCSN)×t	-3.5+(WEN-WCSN)×t	3.5+(WEN-WCSN)×t	ns
WE35	EIM_CSx_B Valid to EIM_OE_B Valid	WE10- WE6+(OEA-RCSA)×t	-3.5+(OEA-RCSA)×t	3.5+(OEA-RCSA)×t	ns
WE35A (muxed A/D)	EIM_CSx_B Valid to EIM_OE_B Valid	WE10-WE6+(OEA+RADVN+RADVA+ADH+1-RCSA)×t	-3.5+(OEA+RADVN+RADVA+ADH+1-RCSA)×t	3.5+(OEA+RADVN+RADVA+ADH+1-RCSA)×t	ns
WE36	EIM_OE_B Invalid to EIM_CSx_B Invalid	WE7-WE11+(OEN-RCSN)×t	-3.5+(OEN-RCSN)×t	3.5+(OEN-RCSN)×t	ns
WE37	EIM_CSx_B Valid to EIM_EBx_B Valid (Read access)	WE12-WE6+(RBEA-RCSA)× t	-3.5+(RBEA- RCSA)×t	3.5+(RBEA - RCSA)×t	ns
WE38	EIM_EBx_B Invalid to EIM_CSx_B Invalid (Read access)	WE7-WE13+(RBEN-RCSN)×t	-3.5+ (RBEN-RCSN)×t	3.5+(RBEN-RCSN)×t	ns
WE39	EIM_CSx_B Valid to EIM_LBA_B Valid	WE14-WE6+(ADVA-CSA)×t	-3.5+ (ADVA-CSA)×t	3.5+(ADVA-CSA)×t	ns

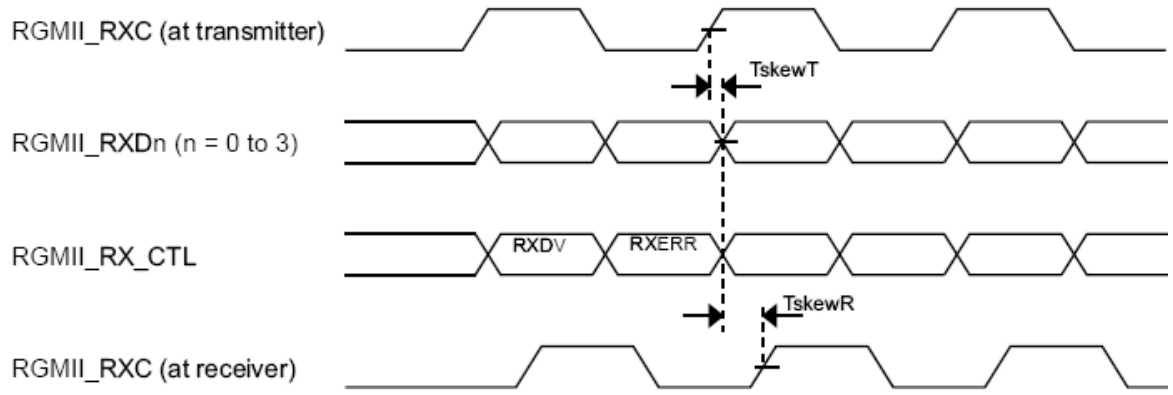

Figure 54. RGMII Receive Signal Timing Diagram Original

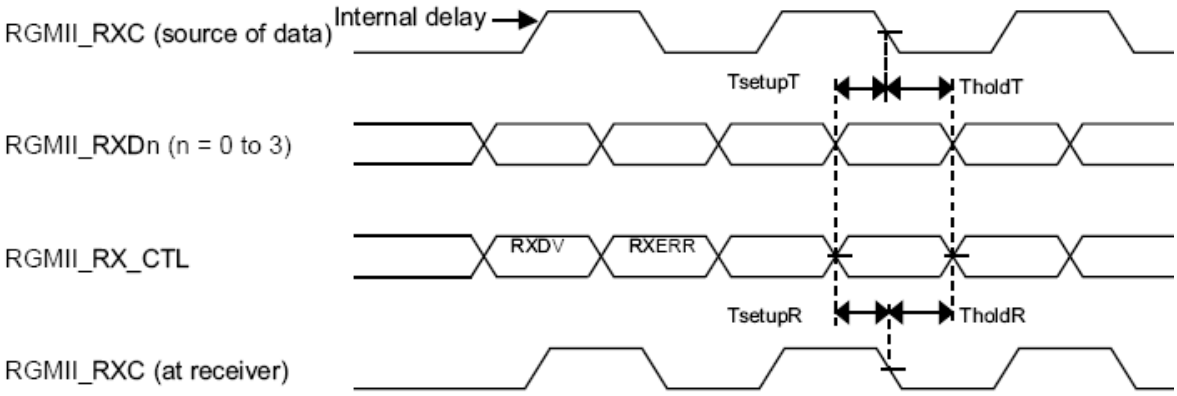

Figure 55. RGMII Receive Signal Timing Diagram with Internal Delay

4.11.6 Flexible Controller Area Network (FlexCAN) AC Electrical Specifications

The Flexible Controller Area Network (FlexCAN) module is a communication controller implementing the CAN protocol according to the CAN 2.0B protocol specification.The processor has two CAN modules available for systems design. Tx and Rx ports for both modules are multiplexed with other I/O pins. See the IOMUXC chapter of the i.MX 6Dual/6Quad reference manual (IMX6DQRM) to see which pins expose Tx and Rx pins; these ports are named FLEXCAN_TX and FLEXCAN_RX, respectively.

4.11.7 HDMI Module Timing Parameters

4.11.7.1 Latencies and Timing Information

Power-up time (time between TX_PWRON assertion and TX_READY assertion) for the HDMI 3D Tx PHY while operating with the slowest input reference clock supported (13.5 MHz) is 3.35 ms.

The maximum accuracy of UP/DOWN edge of IPP_DISP_DATA is:

$$Accuracy = T_{diclk} \pm 0.62ns$$

The DISP_CLK_PERIOD, DI_CLK_PERIOD parameters are register-controlled.

Figure 71 depicts the synchronous display interface timing for access level. The DISP_CLK_DOWN and DISP_CLK_UP parameters are register-controlled. Table 70 lists the synchronous display interface timing characteristics.

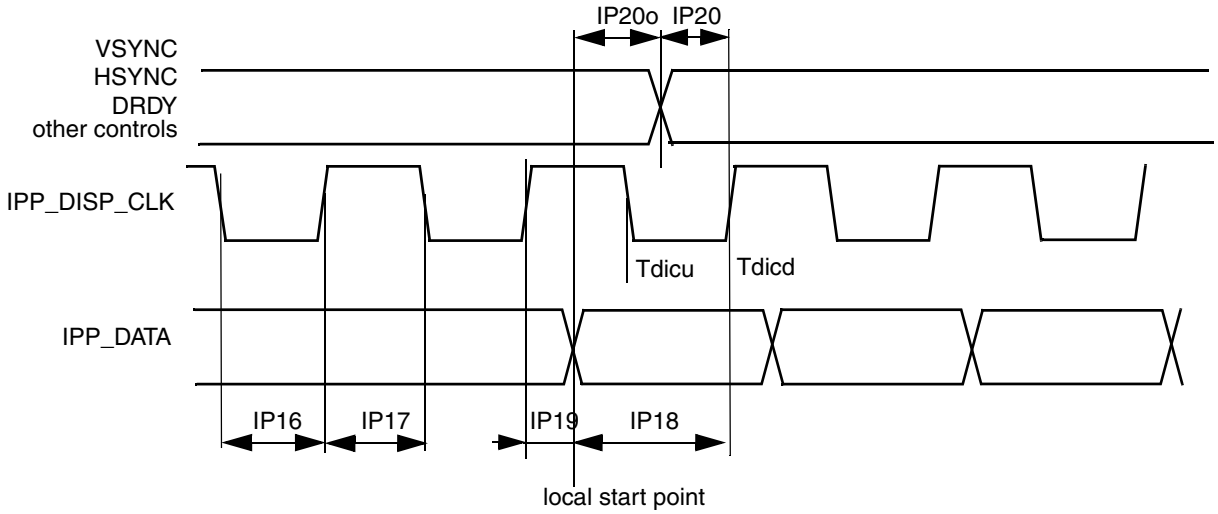

Figure 71. Synchronous Display Interface Timing Diagram—Access Level

Table 70. Synchronous Display Interface Timing Characteristics (Access Level)

ID	Parameter	Symbol	Min	Typ[1]	Max	Unit
IP16	Display interface clock low time	Tckl	Tdicd-Tdicu-1.24	Tdicd[2]-Tdicu[3]	Tdicd-Tdicu+1.24	ns
IP17	Display interface clock high time	Tckh	Tdicp-Tdicd+Tdicu-1.24	Tdicp-Tdicd+Tdicu	Tdicp-Tdicd+Tdicu+1.2	ns
IP18	Data setup time	Tdsu	Tdicd-1.24	Tdicu	—	ns
IP19	Data holdup time	Tdhd	Tdicp-Tdicd-1.24	Tdicp-Tdicu	—	ns
IP20o	Control signals offset times (defined for each pin)	Tocsu	Tocsu-1.24	Tocsu	Tocsu+1.24	ns
IP20	Control signals setup time to display interface clock (defined for each pin)	Tcsu	Tdicd-1.24-Tocsu%Tdicp	Tdicu	—	ns

[1]The exact conditions have not been finalized, but will likely match the current customer requirement for their specific display. These conditions may be chip specific.

[2] Display interface clock down time

$$Tdicd = \frac{1}{2}\left(T_{diclk} \times ceil\left[\frac{2 \times DISP\_CLK\_DOWN}{DI\_CLK\_PERIOD}\right]\right)$$

4.11.12.6 High-Speed Clock Timing

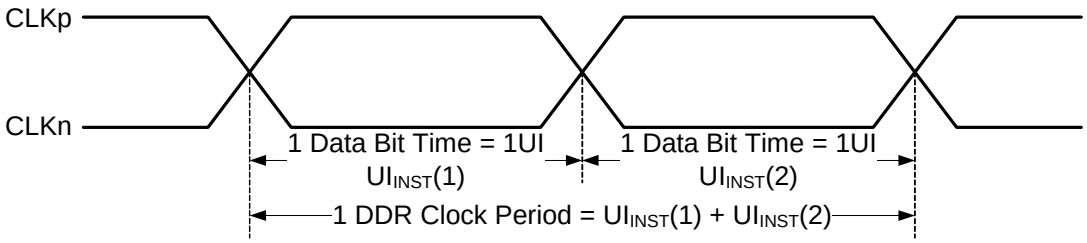

Figure 75. DDR Clock Definition

4.11.12.7 Forward High-Speed Data Transmission Timing

The timing relationship of the DDR Clock differential signal to the Data differential signal is shown in Figure 76:

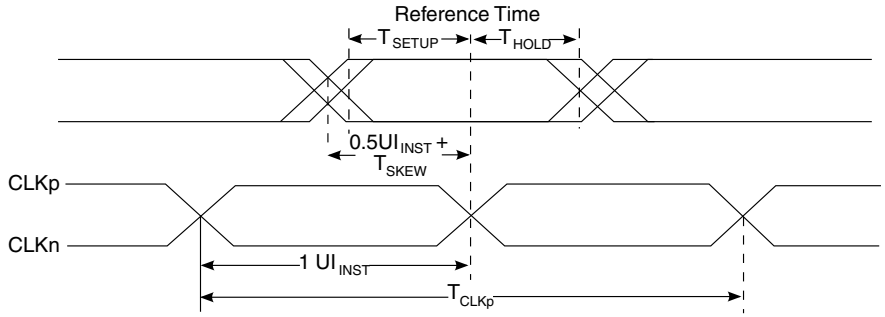

Figure 76. Data to Clock Timing Definitions

4.11.12.8 Reverse High-Speed Data Transmission Timing

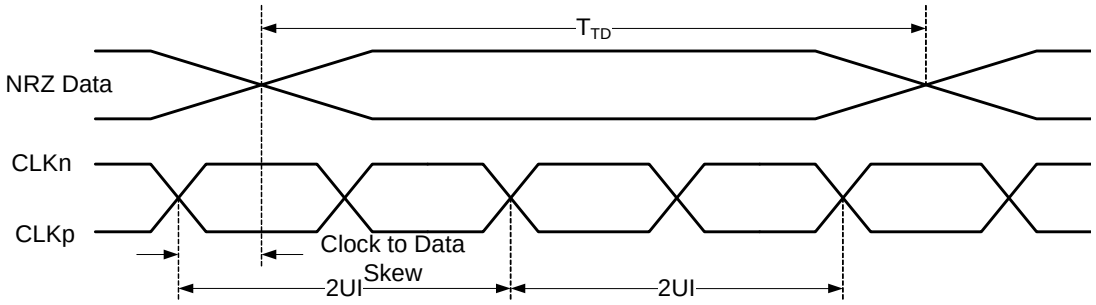

Figure 77. Reverse High-Speed Data Transmission Timing at Slave Side

4.11.13.3 Receiver Real-Time Data Flow

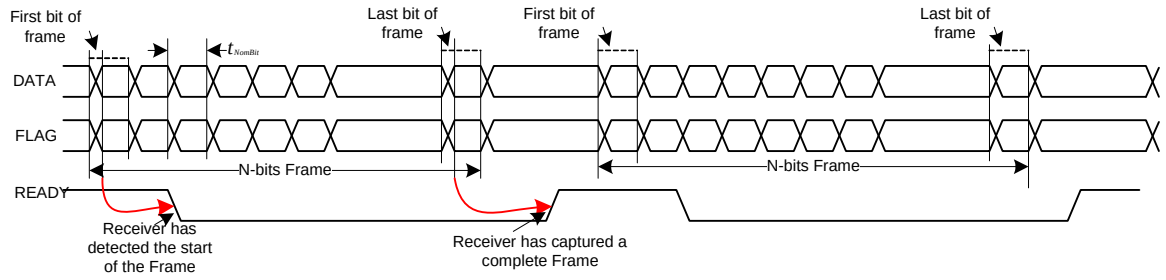

Figure 81. Receiver Real-Time Data Flow READY Signal Timing

4.11.13.4 Synchronized Data Flow Transmission with Wake

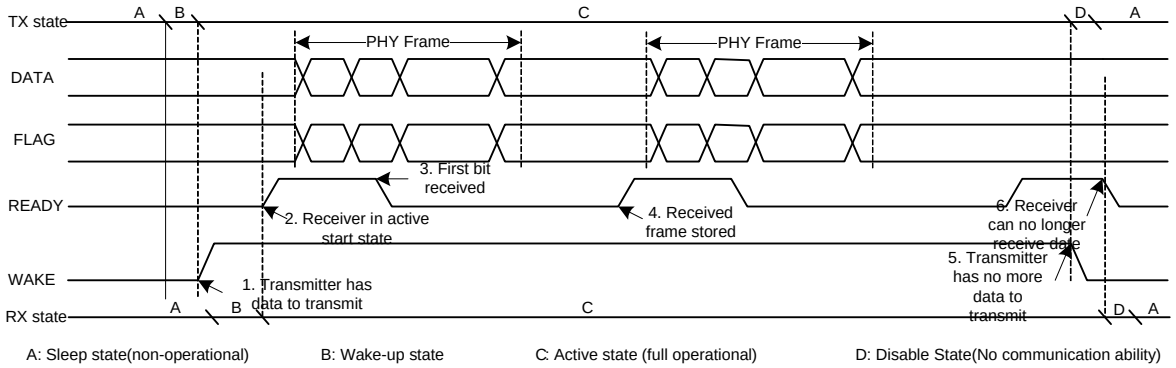

Figure 82. Synchronized Data Flow Transmission with WAKE

4.11.13.5 Stream Transmission Mode Frame Transfer

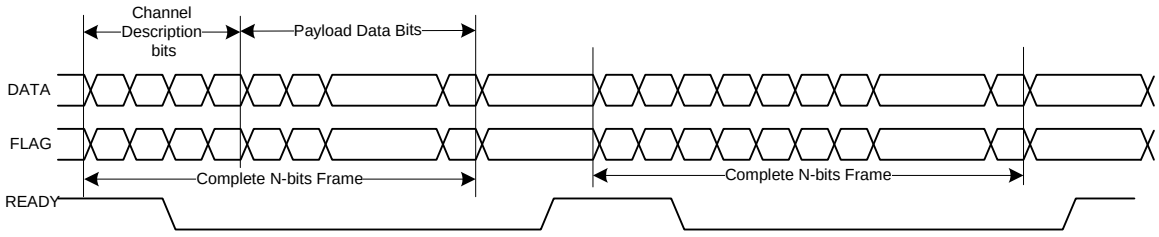

Figure 83. Stream Transmission Mode Frame Transfer (Synchronized Data Flow)

4.11.13.6 Frame Transmission Mode (Synchronized Data Flow)

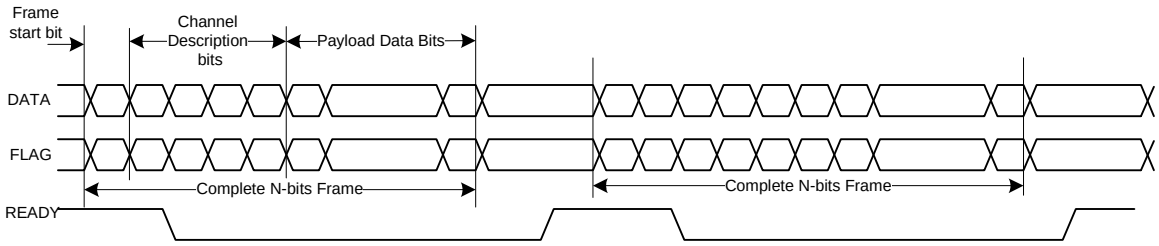

Figure 84. Frame Transmission Mode Transfer of Two Frames (Synchronized Data Flow)

4.11.13.7 Frame Transmission Mode (Pipelined Data Flow)

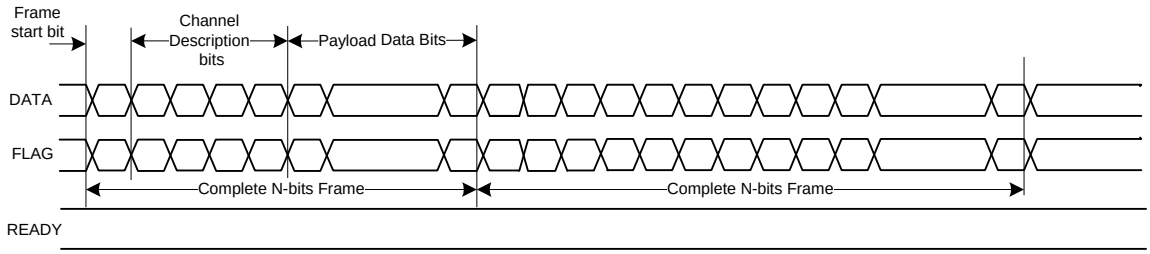

Figure 85. Frame Transmission Mode Transfer of Two Frames (Pipelined Data Flow)

4.11.13.8 DATA and FLAG Signal Timing Requirement for a 15 pF Load

Table 74. DATA and FLAG Timing

Parameter	Description	1 Mbit/s	100 Mbit/s
$t_{Bit, nom}$	Nominal bit time	1000 ns	10 ns
$t_{Rise, min}$ and $t_{Fall, min}$	Minimum allowed rise and fall time	2 ns	2 ns
$t_{TxToRxSkew, maxfq}$	Maximum skew between transmitter and receiver package pins	50 ns	0.5 ns
$t_{EageSepTx, min}$	Minimum allowed separation of signal transitions at transmitter package pins, including all timing defects, for example, jitter and skew, inside the transmitter.	400 ns	4 ns
$t_{EageSepRx, min}$	Minimum separation of signal transitions, measured at the receiver package pins, including all timing defects, for example, jitter and skew, inside the receiver.	350 ns	3.5 ns

Table 77. MLB 256/512 Fs Timing Parameters (continued)

Parameter	Symbol	Min	Max	Unit	Comment
Bus Hold from MLB_CLK low	t_{mdzh}	4	—	ns	—
Transmitter MLBSIG (MLBDAT) output valid from transition of MLBCLK (low-to-high)	Tdelay	—	10.75	—	ns

1 The controller can shut off MLB_CLK to place MediaLB in a low-power state. Depending on the time the clock is shut off, a runt pulse can occur on MLB_CLK.

2 MLB_CLK low/high time includes the pulse width variation.

3 The MediaLB driver can release the MLB_DATA/MLB_SIG line as soon as MLB_CLK is low; however, the logic state of the final driven bit on the line must remain on the bus for t_{mdzh}. Therefore, coupling must be minimized while meeting the maximum load capacitance listed.

Ground = 0.0 V; load capacitance = 40 pF; MediaLB speed = 1024 Fs; Fs = 48 kHz; all timing parameters specified from the valid voltage threshold as listed in Table 78; unless otherwise noted.

Table 78. MLB 1024 Fs Timing Parameters

Parameter	Symbol	Min	Max	Unit	Comment
MLB_CLK Operating Frequency[1]	f_{mck}	45.056	51.2	MHz	1024xfs at 44.0 kHz 1024xfs at 50.0 kHz
MLB_CLK rise time	t_{mckr}	—	1	ns	V_{IL} TO V_{IH}
MLB_CLK fall time	t_{mckf}	—	1	ns	V_{IH} TO V_{IL}
MLB_CLK low time	t_{mckl}	6.1	—	ns	(see [2])
MLB_CLK high time	t_{mckh}	9.3	—	ns	—
MLB_SIG/MLB_DATA receiver input valid to MLB_CLK falling	t_{dsmcf}	1	—	ns	—
MLB_SIG/MLB_DATA receiver input hold from MLB_CLK low	t_{dhmcf}	t_{mdzh}	—	ns	—
MLB_SIG/MLB_DATA output high impedance from MLB_CLK low	t_{mcfdz}	0	t_{mckl}	ns	(see [3])
Bus Hold from MLB_CLK low	t_{mdzh}	2	—	ns	—
Transmitter MLBSIG (MLBDAT) output valid from transition of MLBCLK (low-to-high)	Tdelay	—	6	ns	—

1 The controller can shut off MLB_CLK to place MediaLB in a low-power state. Depending on the time the clock is shut off, a runt pulse can occur on MLB_CLK.

2 MLB_CLK low/high time includes the pulse width variation.

3 The MediaLB driver can release the MLB_DATA/MLB_SIG line as soon as MLB_CLK is low; however, the logic state of the final driven bit on the line must remain on the bus for t_{mdzh}. Therefore, coupling must be minimized while meeting the maximum load capacitance listed.

Table 79 lists the MediaLB 6-pin interface timing characteristics, and Figure 88 shows the MLB 6-pin delay, setup, and hold times.

4.11.20.3 SSI Transmitter Timing with External Clock

Figure 98 depicts the SSI transmitter external clock timing and Table 88 lists the timing parameters for the transmitter timing with the external clock.

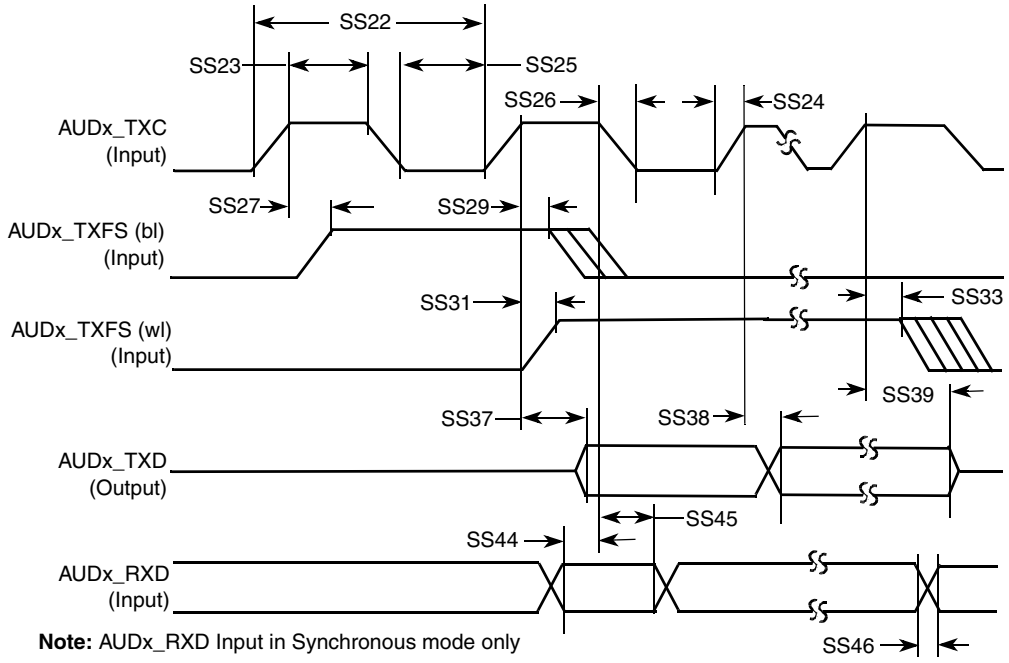

Figure 98. SSI Transmitter External Clock Timing Diagram

Table 88. SSI Transmitter Timing with External Clock

ID	Parameter	Min	Max	Unit
External Clock Operation				
SS22	AUDx_TXC/AUDx_RXC clock period	81.4	—	ns
SS23	AUDx_TXC/AUDx_RXC clock high period	36.0	—	ns
SS24	AUDx_TXC/AUDx_RXC clock rise time	—	6.0	ns
SS25	AUDx_TXC/AUDx_RXC clock low period	36.0	—	ns
SS26	AUDx_TXC/AUDx_RXC clock fall time	—	6.0	ns
SS27	AUDx_TXC high to AUDx_TXFS (bl) high	–10.0	15.0	ns
SS29	AUDx_TXC high to AUDx_TXFS (bl) low	10.0	—	ns
SS31	AUDx_TXC high to AUDx_TXFS (wl) high	–10.0	15.0	ns
SS33	AUDx_TXC high to AUDx_TXFS (wl) low	10.0	—	ns
SS37	AUDx_TXC high to AUDx_TXD valid from high impedance	—	15.0	ns
SS38	AUDx_TXC high to AUDx_TXD high/low	—	15.0	ns
SS39	AUDx_TXC high to AUDx_TXD high impedance	—	15.0	ns

4.11.23 USB PHY Parameters

This section describes the USB-OTG PHY and the USB Host port PHY parameters.

The USB PHY meets the electrical compliance requirements defined in the Universal Serial Bus Revision 2.0 OTG, USB Host with the amendments below (On-The-Go and Embedded Host Supplement to the USB Revision 2.0 Specification is not applicable to Host port).

- USB ENGINEERING CHANGE NOTICE
  - Title: 5V Short Circuit Withstand Requirement Change
  - Applies to: Universal Serial Bus Specification, Revision 2.0
- Errata for USB Revision 2.0 April 27, 2000 as of 12/7/2000
- USB ENGINEERING CHANGE NOTICE
  - Title: Pull-up/Pull-down resistors
  - Applies to: Universal Serial Bus Specification, Revision 2.0
- USB ENGINEERING CHANGE NOTICE
  - Title: Suspend Current Limit Changes
  - Applies to: Universal Serial Bus Specification, Revision 2.0
- USB ENGINEERING CHANGE NOTICE
  - Title: USB 2.0 Phase Locked SOFs
  - Applies to: Universal Serial Bus Specification, Revision 2.0
- On-The-Go and Embedded Host Supplement to the USB Revision 2.0 Specification
  - Revision 2.0 plus errata and ecn June 4, 2010
- Battery Charging Specification (available from USB-IF)
  - Revision 1.2, December 7, 2010
  - Portable device only

Table 99. 21 x 21 mm Supplies Contact Assignment (continued)

Supply Rail Name	Ball(s) Position(s)	Remark
VDDHIGH_CAP	H10, J10	Secondary supply for the 2.5 V domain (internal regulator output—requires capacitor if internal regulator is used)
VDDHIGH_IN	H9, J9	Primary supply for the 2.5 V regulator
VDDPU_CAP	H17, J17, K17, L17, M17, N17, P17	Secondary supply for the VPU and GPU (internal regulator output—requires capacitor if internal regulator is used)
VDDSOC_CAP	R10, T10, T13, T14, U10, U13, U14	Secondary supply for the SoC and PU (internal regulator output—requires capacitor if internal regulator is used)
VDDSOC_IN	H16, J16, K16, L16, M16, N16, P16, R16, T16, U16	Primary supply for the SoC and PU regulators
VDDUSB_CAP	F9	Secondary supply for the 3 V domain (internal regulator output—requires capacitor if internal regulator is used)
ZQPAD	AE17	—

Table 100 displays an alpha-sorted list of the signal assignments including power rails. The table also includes out of reset pad state.

Table 100. 21 x 21 mm Functional Contact Assignments

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition[1]			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value[2]
BOOT_MODE0	C12	VDD_SNVS_IN	GPIO	ALT0	SRC_BOOT_MODE0	Input	PD (100K)
BOOT_MODE1	F12	VDD_SNVS_IN	GPIO	ALT0	SRC_BOOT_MODE1	Input	PD (100K)
CLK1_N	C7	VDD_HIGH_CAP	—	—	CLK1_N	—	—
CLK1_P	D7	VDD_HIGH_CAP	—	—	CLK1_P	—	—
CLK2_N	C5	VDD_HIGH_CAP	—	—	CLK2_N	—	—
CLK2_P	D5	VDD_HIGH_CAP	—	—	CLK2_P	—	—
CSI_CLK0M	F4	NVCC_MIPI	—	—	CSI_CLK_N	—	—
CSI_CLK0P	F3	NVCC_MIPI	—	—	CSI_CLK_P	—	—
CSI_D0M	E4	NVCC_MIPI	—	—	CSI_DATA0_N	—	—
CSI_D0P	E3	NVCC_MIPI	—	—	CSI_DATA0_P	—	—
CSI_D1M	D1	NVCC_MIPI	—	—	CSI_DATA1_N	—	—
CSI_D1P	D2	NVCC_MIPI	—	—	CSI_DATA1_P	—	—
CSI_D2M	E1	NVCC_MIPI	—	—	CSI_DATA2_N	—	—
CSI_D2P	E2	NVCC_MIPI	—	—	CSI_DATA2_P	—	—
CSI_D3M	F2	NVCC_MIPI	—	—	CSI_DATA3_N	—	—

Table 100. 21 x 21 mm Functional Contact Assignments (continued)

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition[1]			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value[2]
PCIE_TXM	A3	PCIE_VPH	—	—	PCIE_TX_N	—	—
PCIE_TXP	B3	PCIE_VPH	—	—	PCIE_TX_P	—	—
PMIC_ON_REQ	D11	VDD_SNVS_IN	GPIO	ALT0	SNVS_PMIC_ON_REQ	Output	Open Drain with PU (100K)
PMIC_STBY_REQ	F11	VDD_SNVS_IN	GPIO	ALT0	CCM_PMIC_STBY_REQ	Output	0
POR_B	C11	VDD_SNVS_IN	GPIO	ALT0	SRC_POR_B	Input	PU (100K)
RGMII_RD0	C24	NVCC_RGMII	DDR	ALT5	GPIO6_IO25	Input	PU (100K)
RGMII_RD1	B23	NVCC_RGMII	DDR	ALT5	GPIO6_IO27	Input	PU (100K)
RGMII_RD2	B24	NVCC_RGMII	DDR	ALT5	GPIO6_IO28	Input	PU (100K)
RGMII_RD3	D23	NVCC_RGMII	DDR	ALT5	GPIO6_IO29	Input	PU (100K)
RGMII_RX_CTL	D22	NVCC_RGMII	DDR	ALT5	GPIO6_IO24	Input	PD (100K)
RGMII_RXC	B25	NVCC_RGMII	DDR	ALT5	GPIO6_IO30	Input	PD (100K)
RGMII_TD0	C22	NVCC_RGMII	DDR	ALT5	GPIO6_IO20	Input	PU (100K)
RGMII_TD1	F20	NVCC_RGMII	DDR	ALT5	GPIO6_IO21	Input	PU (100K)
RGMII_TD2	E21	NVCC_RGMII	DDR	ALT5	GPIO6_IO22	Input	PU (100K)
RGMII_TD3	A24	NVCC_RGMII	DDR	ALT5	GPIO6_IO23	Input	PU (100K)
RGMII_TX_CTL	C23	NVCC_RGMII	DDR	ALT5	GPIO6_IO26	Input	PD (100K)
RGMII_TXC	D21	NVCC_RGMII	DDR	ALT5	GPIO6_IO19	Input	PD (100K)
RTC_XTALI	D9	VDD_SNVS_CAP	—	—	RTC_XTALI	—	—
RTC_XTALO	C9	VDD_SNVS_CAP	—	—	RTC_XTALO	—	—
SATA_RXM	A14	SATA_VPH	—	—	SATA_PHY_RX_N	—	—
SATA_RXP	B14	SATA_VPH	—	—	SATA_PHY_RX_P	—	—
SATA_TXM	B12	SATA_VPH	—	—	SATA_PHY_TX_N	—	—
SATA_TXP	A12	SATA_VPH	—	—	SATA_PHY_TX_P	—	—
SD1_CLK	D20	NVCC_SD1	GPIO	ALT5	GPIO1_IO20	Input	PU (100K)
SD1_CMD	B21	NVCC_SD1	GPIO	ALT5	GPIO1_IO18	Input	PU (100K)
SD1_DAT0	A21	NVCC_SD1	GPIO	ALT5	GPIO1_IO16	Input	PU (100K)
SD1_DAT1	C20	NVCC_SD1	GPIO	ALT5	GPIO1_IO17	Input	PU (100K)
SD1_DAT2	E19	NVCC_SD1	GPIO	ALT5	GPIO1_IO19	Input	PU (100K)
SD1_DAT3	F18	NVCC_SD1	GPIO	ALT5	GPIO1_IO21	Input	PU (100K)
SD2_CLK	C21	NVCC_SD2	GPIO	ALT5	GPIO1_IO10	Input	PU (100K)
SD2_CMD	F19	NVCC_SD2	GPIO	ALT5	GPIO1_IO11	Input	PU (100K)
SD2_DAT0	A22	NVCC_SD2	GPIO	ALT5	GPIO1_IO15	Input	PU (100K)
SD2_DAT1	E20	NVCC_SD2	GPIO	ALT5	GPIO1_IO14	Input	PU (100K)
SD2_DAT2	A23	NVCC_SD2	GPIO	ALT5	GPIO1_IO13	Input	PU (100K)
SD2_DAT3	B22	NVCC_SD2	GPIO	ALT5	GPIO1_IO12	Input	PU (100K)

7 Revision History

Table 103 provides a revision history for this data sheet.

Table 103. i.MX 6Dual/6Quad Data Sheet Document Revision History

Rev. Number	Date	Substantive Change(s)
4	07/2015	• Added footnote to Table 1, "Example Orderable Part Numbers," on page 3: If a 24 MHz input clock is used (required for USB), the maximum SoC speed is limited to 996 MHz. • Section 1.2, “Features” changed Five UARTs, from *up to 4.0 Mbps*, to *up to 5.0 Mbps.* • Table 6, "Operating Ranges," on page 21: Row: VDD_HIGH internal regulator, changed minimum parameter value from 2.8 to 2.7V. • Table 6, "Operating Ranges," on page 21: Removed footnote: *VDDSOC and VDDPU output voltages must be set according to this rule: VDDARM-VDDSOC/PU<50mV.* This was a duplicate footnote, renumbered footnotes accordingly. • Table 6, "Operating Ranges," on page 21: Changed value: *Standby/DSM Mode, VDD_SOC_IN, minimum voltage, from 0.9V to 1.05V.* • Table 8, "Maximum Supply Currents," on page 25, Differentiated VDD_ARM_IN, VDD_ARM23_IN, and VDD_SOC_IN by frequency and by Power Virus/CoreMark maximum current. • Table 21, "XTALI and RTC_XTALI DC Parameters," on page 38, Added rows: *Input capacitance*; *Startup current*; and *DC input current* and their values. • Table 40, "EIM Bus Timing Parameters," on page 53, Changed WE4–WE17 minimum and maximum parameter values from, *0.5 t (k+1)/2-1.25*, to *0.5 x t x (k+1)-1.25.* • Table 41, "EIM Asynchronous Timing Parameters Relative to Chip Select^{1}," on page 60 Added to end of formulas in the minimum, typical, and maximum parameter values for WE31–WE42 and WE45–WE46, $\times t$. For example from *3-CSN*, to *3-CSN*$\times t$. Also added maximum value to MAXDTI of 10. • Table 43, "DDR3/DDR3L Write Cycle," on page 63, Changed minimum parameter value of DDR17 from 240 to 125; and of DDR18 from 240 to 150. • Figure 27, "LPDDR2 Command and Address Timing Diagram," on page 64, LP2 signal cycle reduced. • Table 46, "LPDDR2 Write Cycle," on page 65, Changed LP21 minimum and maximum parameter value from -0.25/+0.25 to 0.8/1.2. • Figure 41, "ECSPI Master Mode Timing Diagram," on page 76, Added footnote: *Note: ECSPIx_MOSI is always driven (not tri-stated) between actual data transmissions. This limits the ECSPI to be connected between a single master and a single slave.* • Figure 42, "ECSPI Slave Mode Timing Diagram," on page 77, Added footnote: *Note: ECSPIx_MISO is always driven (not tri-stated) between actual data transmissions. This limits the ECSPI to be connected between a single master and a single slave.* • Figure 65, "Gated Clock Mode Timing Diagram," on page 98, Corrected IPU2_CSIx_HSYNC trace drawing. • Section 4.11.23, “USB PHY Parameters” Specified *Battery Charging Specification* applies to portable devices only.